

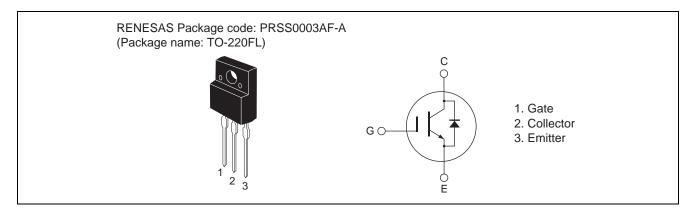
RJH60V3BDPP-M0

600V - 17A - IGBT Application: Inverter R07DS0761EJ0100 Rev.1.00 May 25, 2012

Features

- Short circuit withstand time (6 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)}=1.6~V$ typ. (at $I_C=17~A,~V_{GE}=15~V,~Ta=25^{\circ}C$)
- Built in fast recovery diode (25 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching $t_f=75$ ns typ. (at $V_{CC}=300$ V, $V_{GE}=15$ V, $I_C=17$ A, Rg=5 Ω , Ta=25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	I _C	35	A
	Tc = 100°C	I _C	17	A
Collector peak current		ic(peak) Note1	70	A
Collector to emitter diode forward current		i _{DF}	17	A
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	70	A
Collector dissipation		P _C Note2	40	W
Junction to case thermal resistance (IGBT)		θj-c Note2	3.15	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	2.5	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

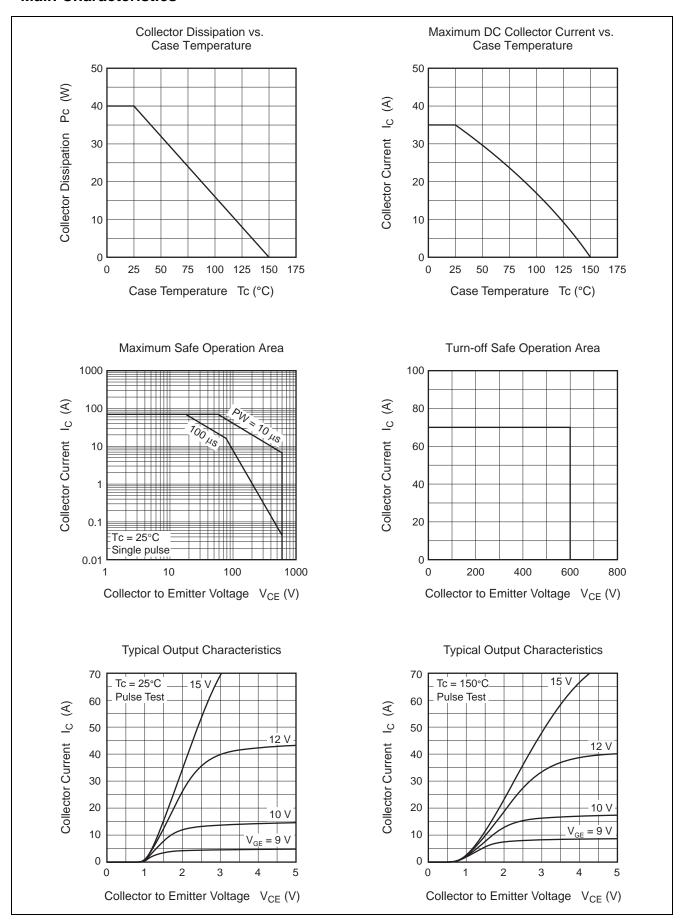
Electrical Characteristics

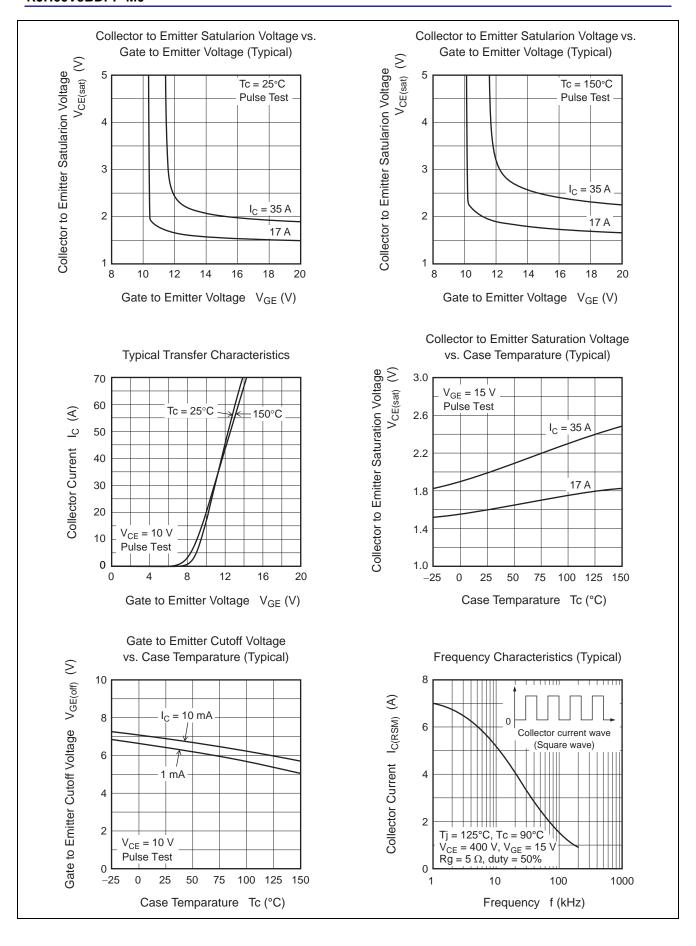
Item	Symbol	Min	Тур	Max	Unit	(Ta = 25°C	
Collector to emitter breakdown voltage	V _{(BR)CES}	600		_	V	$I_C = 10 \mu A, V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	V _{CE} = 600 V, V _{GE} = 0	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	5.5	_	7.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.6	2.2	V	$I_C = 17 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.0	_	V	$I_C = 35 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	880	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	60	_	pF	V _{GE} = 0 f = 1 MHz	
Reverse transfer capacitance	Cres	_	35	_	pF		
Total gate charge	Qg	_	60	_	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	9	_	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc	_	35	_	nC	$I_C = 17 A$	
Turn-on delay time	t _{d(on)}	_	40	_	ns	V _{CC} = 300 V	
Rise time	t _r	_	20	_	ns	$V_{GE} = 15 \text{ V}$	
Turn-off delay time	t _{d(off)}	_	90	_	ns	$I_C = 17 \text{ A}$ $Rg = 5 \Omega$	
Fall time	t _f	_	75	_	ns		
Turn-on energy	Eon	_	0.09	_	mJ	Inductive load	
Turn-off energy	E _{off}	_	0.30	_	mJ	1	
Total switching energy	E _{total}	_	0.39	_	mJ		
Short circuit withstand time	t _{sc}	3	6	_	μS	Tc = 100 °C	
						$V_{GC}\leq 360~V,~V_{GE}=15~V$	
FRD forward voltage	V _F	_	2.8	_	V	I _F = 17 A ^{Note3}	

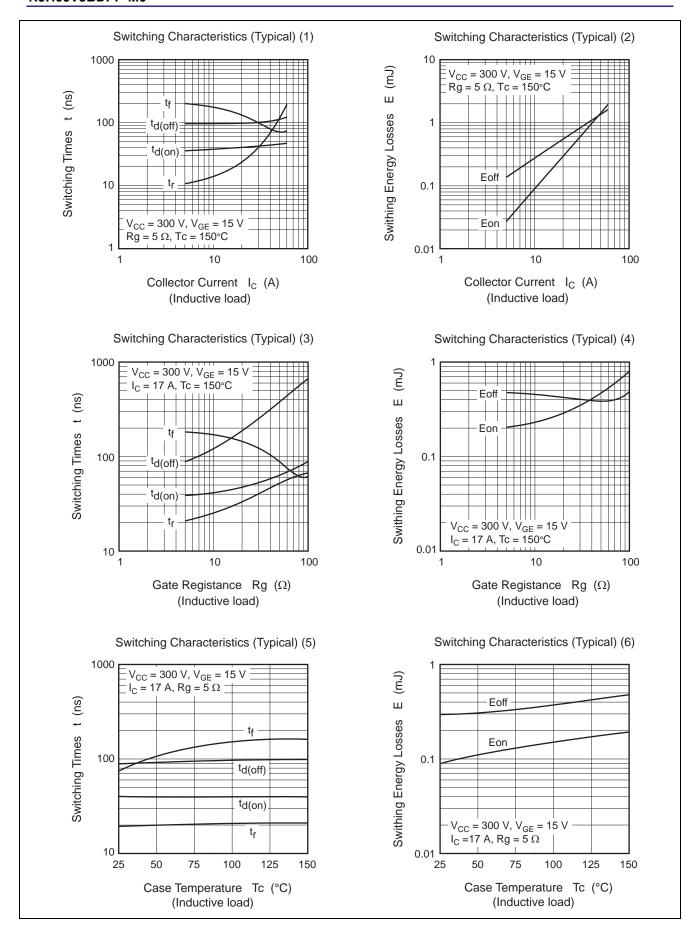
FRD forward voltage	V_{F}	_	2.8	_	V	$I_F = 17 A^{\text{Note3}}$
FRD reverse recovery time	t _{rr}	_	25	_	ns	I _F = 17 A
FRD reverse recovery charge	Qrr	_	0.02	_	μС	di _F /dt = 100 A/μs
FRD peak reverse recovery current	Im	_	1.2	_	Α	

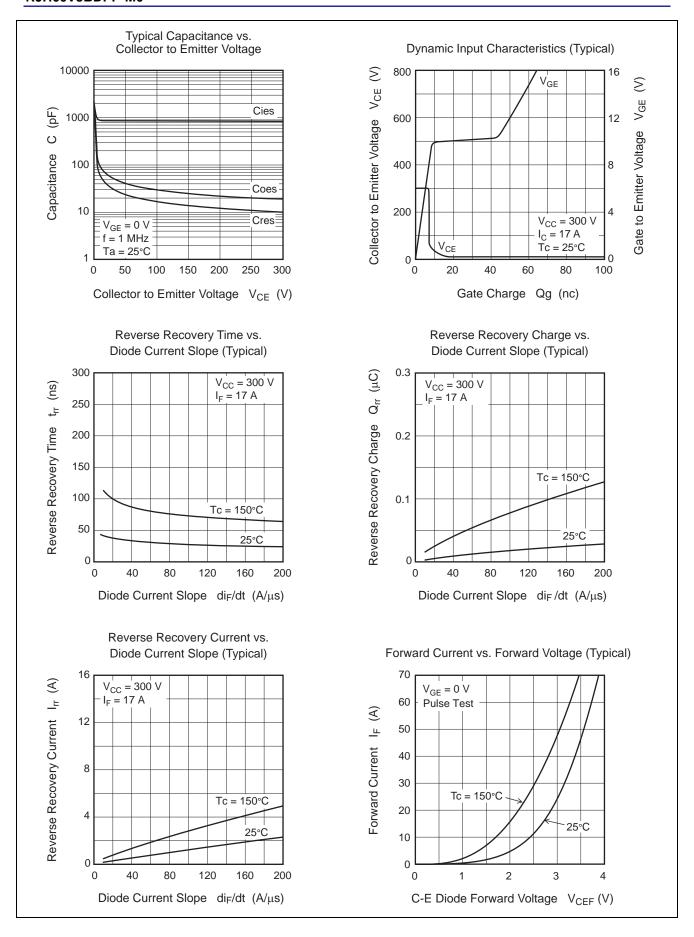
Notes: 3. Pulse test.

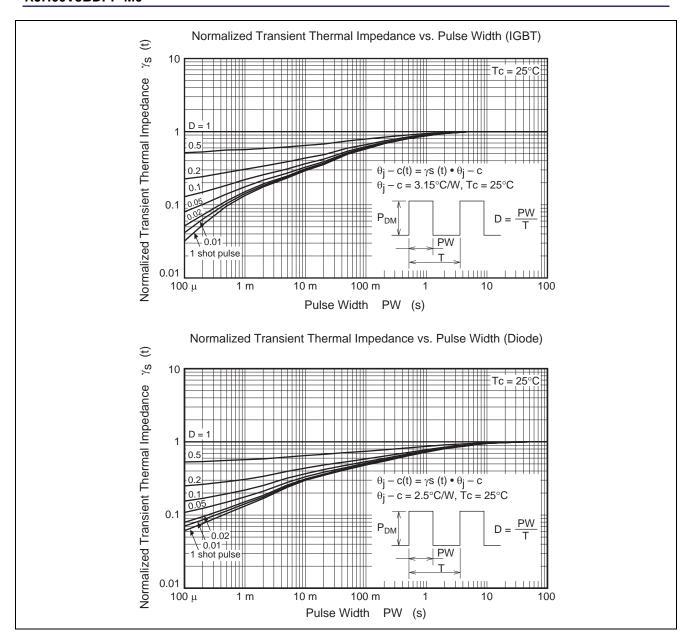
Main Characteristics

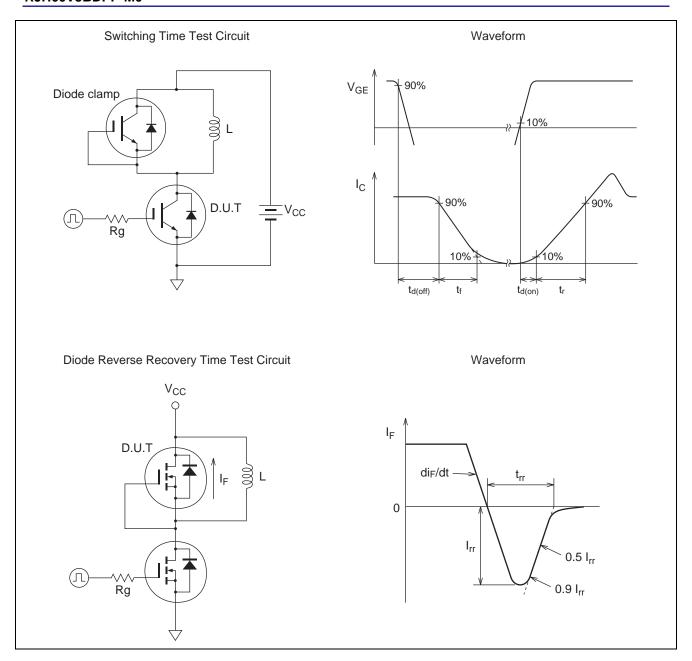




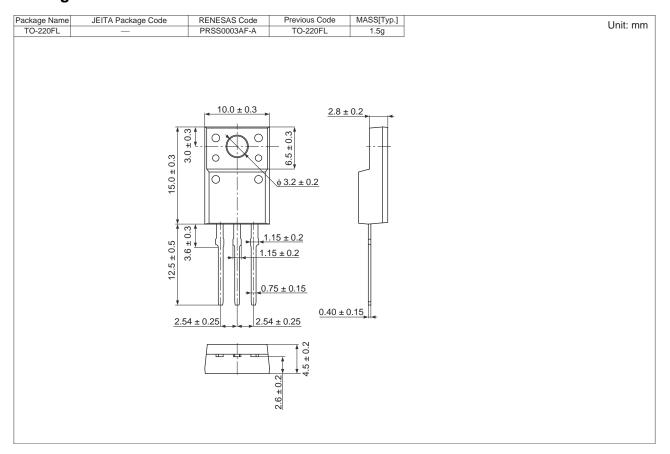








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60V3BDPP-M0#T2	600 pcs	Box (Tube)

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